4.6 Small-Signal Operation and Models

Reading Assignment: pp. 287-294

Recall the small-signal analysis we performed on a junction diode.

We can do a similar analysis on MOSFET amplifiers in order to determine their small-signal gain!

Remember there were essentially three steps:

1.

HO: Small-Signal Response of MOSFET Circuits

HO: Small-Signal Output Resistance

2.

HO: The MOSFET Small-Signal Model

3.



HO: Steps for Small-Signal Analysis

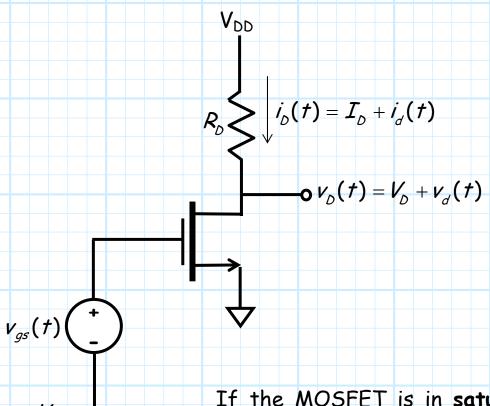
Example: A Small-Signal Analysis of a MOSFET Amp

Example: Another Small-Signal Analysis of a MOSFET Amp

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Small-Signal Response of MOSFET Circuits

Consider this circuit, which has both a **DC** and an AC **small-signal** source. As a result, each voltage and current in the circuit has **both** a DC and small-signal component.



If the MOSFET is in saturation, then the total drain current is:

$$i_{D} = K (v_{GS} - V_{t})^{2}$$

$$= K (V_{GS} + v_{gS} - V_{t})^{2}$$

$$= K (V_{GS} - V_{t})^{2} + 2K (V_{GS} - V_{t}) v_{gS} + K v_{gS}^{2}$$

By looking at this equation, we find that the **third** term is **small** in comparison to the second **if**:

$$V_{gs} \ll 2(V_{GS} - V_{t})$$

We call this equation the **small-signal** condition. For this case, we find that the drain current is:

$$i_{D}(t) = I_{D} + i_{d}(t)$$

$$\approx K \left(V_{GS} - V_{t}\right)^{2} + 2K \left(V_{GS} - V_{t}\right) V_{gS}(t)$$

Thus, it is evident that the DC equation is:

$$I_D = K (V_{GS} - V_t)^2$$

while the small signal equation is:

$$i_{d}(t) = 2K(V_{GS} - V_{t})v_{gS}(t)$$

Thus, we can define the MOSFET transconductance as:

$$g_m \doteq \frac{i_d}{v_{gs}} = 2K \left(V_{GS} - V_t \right)$$

Note this small-signal parameter g_m can likewise be **derived** from a small-signal analysis of the drain current:

$$i_{d}(t) = \frac{d i_{D}}{d v_{GS}} \bigg|_{v_{GS} = V_{GS}} v_{gs}(t)$$

$$= 2K \left(v_{GS} - V_{t} \right) \bigg|_{v_{GS} = V_{GS}} v_{gs}(t)$$

$$= 2K \left(V_{GS} - V_{t} \right) v_{gs}(t)$$

$$= g_{m} v_{as}(t)$$

The MOSFET transconductance relates a small **change** in v_{es} to a small **change** in drain current i_D . This change is completely dependent on the **DC** bias point of the MOSFET, V_{es} and I_D .

We can likewise determine the small signal voltage $v_{ds}(t)$. Writing the KVL for the drain-source leg, we find:

$$V_{DD} - R_D i_D = V_{DS}$$

$$V_{DD} - R_D (I_D + i_d) = V_{DS} + V_{dS}$$

$$V_{DD} - R_D I_D - R_D i_d = V_{DS} + V_{dS}$$

The **DC** equation is therefore:

$$V_{DD} - R_D I_D = V_{DS}$$

while the small-signal equation is:

$$-R_{D} i_{d}(t) = V_{ds}(t)$$

Since $i_d(t) = g_m v_{gs}(t)$, we find that the small-signal voltage $v_{ds}(t)$ is related to $v_{gs}(t)$ as:

$$v_{ds}(t) = -R_D i_d(t)$$
$$= -R_D g_m v_{qs}(t)$$

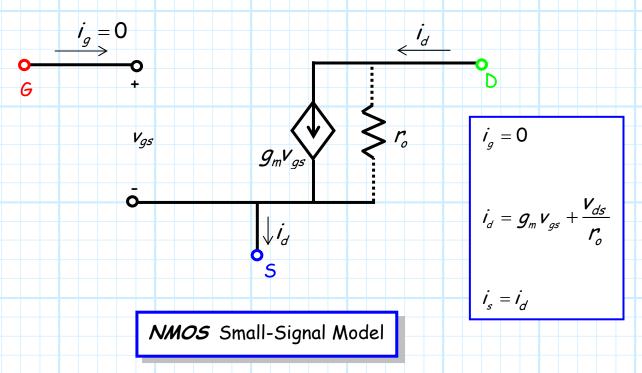
or:

$$\frac{v_{ds}(t)}{v_{gs}(t)} = -R_D g_m$$

Thus, if $R_D g_m \gg 1$, we have small-signal voltage gain.

The MOSFET Small-Signal Model

To determine the small-signal performance of a given MOSFET amplifier circuit, we can replace the BJT with its small-signal model:



Note that this model is **simpler** than the equivalent BJT model, as there is **no** equivalent to small-signal resistance r_{π} (i.e., $r_{\pi} = \infty$).

What this means is that the change in $i_{\mathcal{G}}$ with respect to a change in $v_{\mathcal{GS}}$ is **zero** ($d i_{\mathcal{G}}/dv_{\mathcal{GS}}=0$). But of course we knew this, as $i_{\mathcal{G}}=0$ always—the gate current **never** changes!

MOSFET Output Resistance

Recall that due to channel-length modulation, the MOSFET drain current is slightly dependent on v_{DS} , and thus is more accurately described as:

$$i_D = K (v_{GS} - V_t)^2 (1 + \lambda v_{DS})$$

In order to determine the relationship between the small-signal voltage v_{gs} and small-signal current i_d we can apply a **small-signal analysis** of this equation:

$$i_{d} = \frac{d i_{D}}{d v_{GS}} \bigg|_{v_{GS} = V_{GS}} v_{gS}$$

$$= 2K \left(v_{GS} - V_{t} \right) \bigg|_{v_{GS} = V_{GS}} v_{gS}$$

$$= 2K \left(V_{GS} - V_{t} \right) v_{gS}$$

$$= g_{m} v_{gS}$$

Note that we evaluated the derivative at the DC bias point V_{GS} . The result, as we expected, was the **transconductance** g_m .

We can likewise determine the relationship between small-signal voltage v_{ds} and the small-signal current i_d :

$$i_{d} = \frac{d i_{D}}{d v_{DS}} \Big|_{v_{GS} = V_{GS}} v_{ds}$$

$$= \lambda K \left(v_{GS} - V_{t} \right)^{2} \Big|_{v_{GS} = V_{GS}} v_{ds}$$

$$= \lambda K \left(V_{GS} - V_{t} \right)^{2} v_{ds}$$

$$= \frac{v_{ds}}{r_{o}}$$

where we recall that r_o is the MOSFET output resistance:

$$r_o = \frac{1}{\lambda K (V_{GS} - V_t)^2}$$
$$= \frac{1}{\lambda I_D}$$

The small signal drain current i_d of a MOSFET(biased at a DC operating point I_D , V_{GS}) is therefore:

$$i_d = g_m v_{gs} + \frac{v_{ds}}{r_o}$$

where:

$$g_m = 2K(V_{GS} - V_t)$$

$$r_o = \frac{1}{\lambda K (V_{GS} - V_t)^2}$$

MOSFET Small-Signal Analysis Steps

Complete each of these steps if you choose to correctly complete a MOSFET Amplifier small-signal analysis.

Step 1: Complete a D.C. Analysis

Turn off all small-signal sources, and then complete a circuit analysis with the remaining D.C. sources only.

- * Complete this DC analysis exactly, precisely, the same way you performed the DC analysis in section 4.3. That is, you assume (the saturation mode), enforce, analyze, and check (do not forget to check!).
- * Note that you enforce and check exactly, precisely the same the same equalities and inequalities as discussed in section 4.3.
- * Remember, if we "turn off" a voltage source $(e.g., v_i(t) = 0)$, it becomes a short circuit.
- * However, if we "turn off" a current source (e.g., $i_i(t) = 0$), it becomes an open circuit!

Small-signal amplifiers frequently employ large capacitors. Remember, the impedance of a capacitor at DC is infinity—a DC open circuit.

The goal of this DC analysis is to determine:

- 1) The DC voltage V_{GS} for each MOSFET.
- 2) The DC voltage V_{DS} for each MOSFET (you need this value for the CHECK).

You do not **necessarily** need to determine any other DC currents or voltages within the amplifier circuit!

Once you have found these values, you can CHECK your active assumption, and then move on to step 2.

<u>Step 2:</u> Calculate the small-signal circuit parameters for each MOSFET.

Recall that we now understand 2 MOSFET small-signal parameters:

$$g_m = 2K(V_{GS} - V_t) \qquad r_o = \frac{1}{\lambda K(V_{GS} - V_t)^2}$$

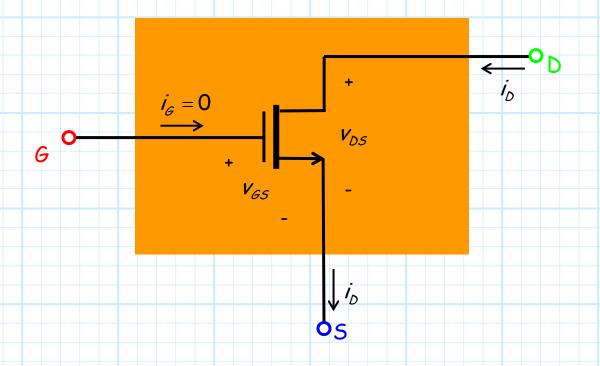
Step 3: Carefully replace all MOSFETs with their small-signal circuit model.

This step often gives students fits!

However, it is actually a very simple and straight-forward step. It does require four important things from the student—patience, precision, persistence and professionalism!

First, note that a MOSFET is:

A device with **three** terminals, called the gate, drain, and source. Its behavior is described in terms of current i_D and voltages v_{GS} , v_{DS} .

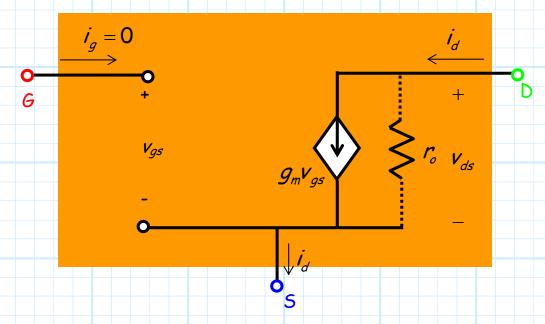


Now, contrast the MOSFET with its small-signal circuit model.

A MOSFET small-signal circuit model is:

A device with **three** terminals, called the gate, drain, and source. Its behavior is described in terms of current i_d and voltages v_{qs} , v_{ds} .

Exactly the same—what a coincidence!



Therefore, replacing a MOSFET with its small-signal circuit model is very simple—you simply change the stuff within the orange box!

Note the parts of the circuit **external** to the orange box do not change! In other words:

1) every device attached to the MOSFET terminals (i.e, gate, drain, source) is attached in precisely the same way to the terminals of the circuit model.

2) every external voltage or current (e.g., v_i , v_o , i_R) is defined in **precisely** the same way both before and after the MOSFET is replaced with its circuit model is (e.g., if the output voltage is the drain voltage in the MOSFET circuit, then the output voltage is **still** the drain voltage in the small-signal circuit!).

Step 4: Set all D.C. sources to zero.

Remember:

A zero voltage DC source is a short.

A zero current DC source is an open.

The schematic in now in front of you is called the small-signal circuit. Note that it is missing two things—DC sources and MOSFET transistors!

- * Note that steps three and four are reversible. You could turn off the DC sources first, and then replace all MOSFETs with their small-signal models—the resulting small-signal circuit will be the same!
- * You will find that the small-signal circuit schematic can often be greatly **simplified**. Once the DC voltage sources are turned **off**, you will find that the terminals of many devices are connected to **ground**.

- * Remember, all terminals connected to ground are also connected to each other! For example, if the source terminal is connected to ground, and one terminal of a resistor is connected to ground, then that resistor terminal is connected to the source!
- * As a result, you often find that resistors in different parts of the circuit are actually connected in **parallel**, and thus can be **combined** to simplify the circuit schematic!
- * Finally, note that the AC impedance of a very large capacitor (i.e., $|Z_{\mathcal{C}}| = 1/\omega \mathcal{C}$) is small for all but the lowest frequencies ω . If this impedance is smaller than the other circuit elements (e.g., < 10Ω), we can view the impedance as approximately zero, and thus replace the large capacitor with a (AC) short!

Organizing and simplifying the small-signal circuit will pay big rewards in the next step, when we analyze the small-signal circuit.

Step 5: Analyze small-signal circuit.

We now can analyze the small-signal circuit to find all small-signal voltages and currents.

- * For small-signal amplifiers, we typically attempt to find the small-signal output voltage v_o in terms of the small-signal input voltage v_i . From this result, we can find the voltage gain of the amplifier.
- * Note that this analysis requires only the knowledge you acquired in EECS 211! The small-signal circuit will consist entirely of resistors and (small-signal) voltage/current sources. These are precisely the same resistors and sources that you learned about in EECS 211. You analyze them in precisely the same way.
- * Do **not** attempt to insert any MOSFET knowledge into your small-signal circuit analysis—there are **no** MOSFETs in a small-signal circuit!!!!!
- * Remember, the MOSFET circuit model contains all of our MOSFET small-signal knowledge, we do not—indeed must not—add any more information to the analysis.

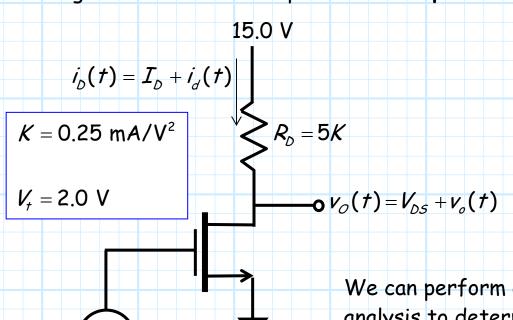
You must trust completely the MOSFET small-signal circuit model. It will give you the correct answer!

 $v_i(t)$

 $4.0 V^{-}$

Example: A Small-Signal Analysis of a MOSFET Amplifier

Let's again consider this simple NMOS Amplifier:



We can perform a small-signal analysis to determine the small-signal open-circuit voltage gain A_o :

$$A_o = \frac{V_o(t)}{V_i(t)}$$

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Step 1: DC Analysis

Turning off the small signal source leaves a DC circuit of:

We ASSUME saturation, so that we ENFORCE:

$$I_{D} = K (V_{GS} - V_{t})^{2}$$

 $R_D = 5K$

15.0 V

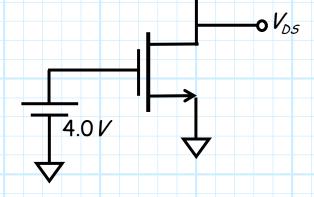
It is evident that:

$$V_{65} = 4.0 \text{ V}$$

Therefore the DC drain current is:

$$I_D = K (V_{GS} - V_t)^2$$

= 0.25(4 - 2)²
= 1.0 mA



Thus, the DC voltage V_{DS} can be determined from KVL as:

$$V_{DS} = 15.0 - I_{D}R_{D}$$

= 15.0 - 1(5)
= 10.0 V

We CHECK our results and find:

$$V_{GS} = 4.0 > V_{t} = 2.0$$

and:

$$V_{DS} = 10.0 > V_{GS} - V_{t} = 2.0$$

Step 2: Determine the small-signal parameters

We find that the transconductance is:

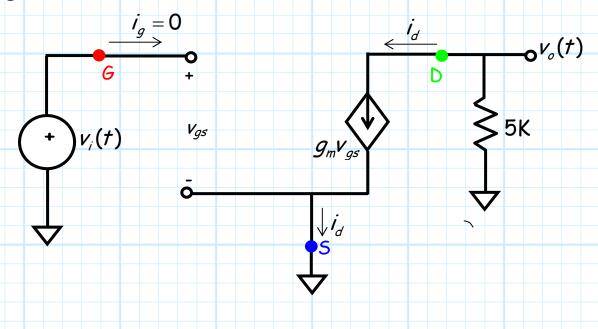
$$g_m = 2K(V_{GS} - V_f)$$

= 2(0.25)(4.0 - 2.0)
= 1 mA/V

Note that **no** value of λ was given, so we will assume $\lambda=0$, and thus **output resistance** $r_o=\infty$.

Steps 3 and 4: Determine the small-signal circuit

We now turn off the **two** DC voltage source, and replace the MOSFET with its **small signal model**. The result is our **small-signal circuit**:



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Step 5: Analyze the small-signal circuit

The analysis of this small-signal circuit is fairly straightforward. First, we note that:

$$V_{qs} = V_i$$

and that:

$$i_d = g_m v_{gs}$$

$$= 1.0 v_{gs}$$

$$= v_{gs}$$

and that:

$$v_o = -5i_d$$

Combing these equations, we find that:

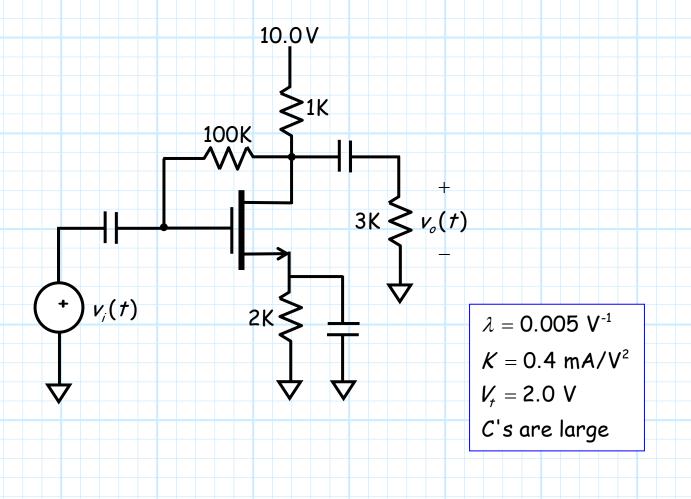
$$v_o = -5 v_i$$

And thus the small-signal open-circuit voltage gain of this amplifier is:

$$A_o = \frac{v_o(t)}{v_i(t)} = -5.0$$

Example: Another Small-Signal Analysis of a MOSFET Amplifier

Let's determine the small-signal voltage gain $A_i = v_o/v_i$ (note not the open-circuit gain!) of the following amplifier:



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Step 1: DC Analysis

Capacitors are open circuits at DC, therefore the DC circuit is:

We ASSUME the MOSFET is in saturation, thus we ENFORCE:

$$I_D = K (V_{GS} - V_t)^2$$

Since $I_{\mathcal{G}} = 0$, we find that $V_{\mathcal{G}} = V_{\mathcal{D}}$, and thus $V_{\mathcal{GS}} = V_{\mathcal{DS}}$. From KVL, we find:

$$10.0 - (1) I_D - V_{DS} - (2) I_D = 0$$



$$V_{GS} = 10.0 - 3I_{D}$$

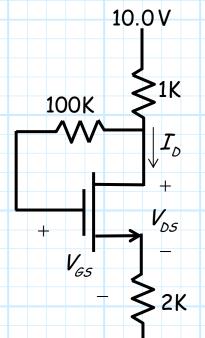
Combining this with $I_D = K(V_{GS} - V_t)^2$, we get a quadratic equation of V_{GS} :

$$V_{GS} = 10.0 - 3K \left(V_{GS} - V_{t}\right)^{2}$$

The solutions to this equation are:

$$V_{GS} = 4.2 \text{ V}$$
 and $V_{GS} = -1.0 \text{ V}$

Don't panic! Only **one** of these solutions satisfy our saturation assumption: $V_{GS} = 4.2 > 2.0 = V_{t}$.



Step 2: Determine Small-Signal Parameters

$$g_m = 2K(V_{GS} - V_t)$$

= 2(0.4)(4.2 - 2.0)
= 1.76 mA/V

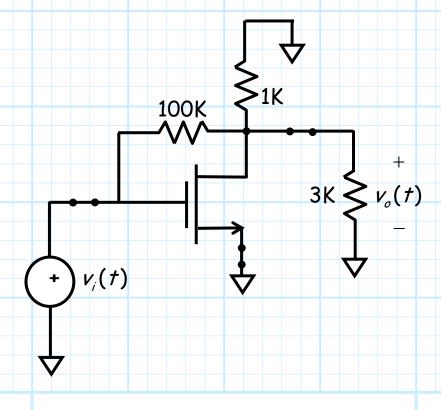
$$r_o = \frac{1}{\lambda K (V_{GS} - V_t)^2}$$

$$= \frac{1}{0.005 (0.4) (4.2 - 2.0)^2}$$

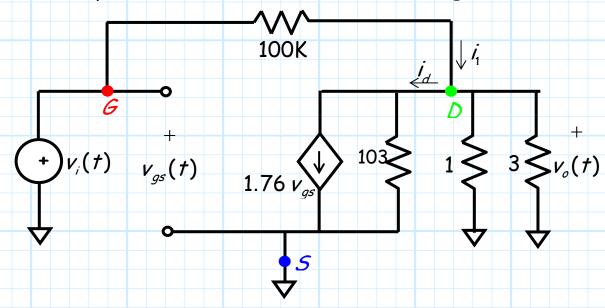
$$= 103 \text{ K}\Omega$$

Steps 3 and 4: Determine the small-signal circuit

- a) Turn off the DC voltage source.
- b) Replace the large capacitors with short circuits.



c) Replace the MOSFET with its small-signal model.



We find first that $v_{gs} = v_i$. We likewise see from KCL that current i_1 is:

$$i_1 = 1.76 v_{gs} + \frac{v_o}{1} + \frac{v_o}{3} + \frac{v_o}{103}$$

$$= 1.76 v_i + 1.334 v_o$$

From Ohm's Law, we likewise find that i_1 is:

$$i_1 = \frac{v_i - v_o}{100}$$

Combining these two equations, we find:

$$v_i - v_o = 176 v_i + 133.4 v_o$$

And from this we find that the small-signal voltage gain is:

$$A_i = \frac{v_o}{v_i} = \frac{-175}{134.4} = -1.31$$
 not much gain!